

L Number	Hits	Search Text	DB	Time stamp
1	0	1996-0002744	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:03
2	0	"19960002744"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:03
3	161	"0002744"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:03
4	27	"0002744" and "1996"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:05
5	0	"0002744" and (isolat\$3 near film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:06
6	49	method near form\$3 near element near isolat\$3 near film	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:25
7	4863	257/51,347,377,382,384,412,413.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:26
8	37	257/51,347,377,382,384,412,413.ccls. and (((isolat\$3 oxide) near (layer film)) with (pn adj junction))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:38
9	357243	257/\$.ccls. 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:36
10	0	257/51,347,377,382,384,412,413.ccls. and (ONO with ((isolat\$3 oxide) near (layer film)) with (pn adj junction))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:36
11	2	(257/\$.ccls. 438/\$.ccls.) and (ONO with ((isolat\$3 oxide) near (layer film)) with (pn adj junction))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:49
12	703	(257/\$.ccls. 438/\$.ccls.) and (((isolat\$3 oxide) near (layer film)) with (pn adj junction))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:38

13	52	((257/\$.ccls. 438/\$.ccls.) and (((isolat\$3 oxide) near (layer film)) with (pn adj junction))) and (ONO (oxide near nitride near oxide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:50
14	3	(ONO (oxide near nitride near oxide)) with ((isolat\$3 oxide) near (layer film)) with (pn adj junction)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:50
15	1075	((isolat\$3 oxide) near (layer film)) with (pn adj junction)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:50
16	73	(((isolat\$3 oxide) near (layer film)) with (pn adj junction)) and (ONO (oxide near nitride near oxide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/16 13:51